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Jameco Part Number 1655990



LOW SKEW, 1-TO-4 DIFFERENTIAL-TO-LVDS FANOUT BUFFER

ICS8543

General Description



The ICS8543 is a low skew, high performance 1-to-4 Differential-to-LVDS Clock Fanout Buffer and a member of the HiPerClockS[™] family of High Performance Clock Solutions from IDT. Utilizing Low Voltage Differential Signaling (LVDS) the ICS8543

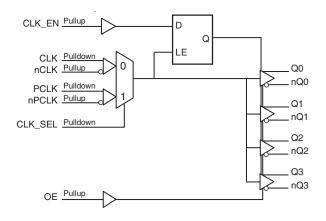
provides a low power, low noise, solution for distributing clock signals over controlled impedances of $100\Omega.$ The ICS8543 has two selectable clock inputs. The CLK, nCLK pair can accept most standard differential input levels. The PCLK, nPCLK pair can accept LVPECL, CML, or SSTL input levels. The clock enable is internally synchronized to eliminate runt pulses on the outputs during asynchronous assertion/deassertion of the clock enable pin.

Guaranteed output and part-to-part skew characteristics make the ICS8543 ideal for those applications demanding well defined performance and repeatability.

Features

- · Four differential LVDS output pairs
- · Selectable differential CLK/nCLK or LVPECL clock inputs
- CLK/nCLK pair can accept the following differential input levels: LVPECL, LVDS, LVHSTL, SSTL, HCSL
- PCLK/nPCLK pair can accept the following differential input levels: LVPECL, CML, SSTL
- Maximum output frequency: 800MHz
- Translates any single-ended input signals to LVDS levels with resistor bias on nCLK input
- Output skew: 40ps (maximum)
- Part-to-part skew: 500ps (maximum)
- Propagation delay: 2.6ns (maximum)
- Full 3.3Vsupply mode
- 0°C to 70°C ambient operating temperature
- Available in both standard (RoHS 5) and lead-free (RoHS 6) packages

Block Diagram



Pin Assignment

GND□	1	20	HQ0
CLK EN	2	19	Figo
	I ⁻		
CLK_SEL□	3	18	
CLK□	4	17	□Q1
nCLK	5	16	□nQ1
PCLK□	6	15	□ Q2
nPCLK□	7	14	nQ2
OE□	8	13	□GND
GND□	9	12	□ Q3
V _{DD} □	10	11	□nQ3

ICS8543

20-Lead TSSOP 6.5mm x 4.4mm x 0.925mm package body G Package Top View

Table 1. Pin Descriptions

Number	Name	Т	уре	Description	
1, 9, 13	GND	Power		Power supply ground.	
2	CLK_EN	Input	Pullup	Synchronizing clock enable. When HIGH, clock outputs follows clock input. When LOW, Qx outputs are forced low, nQx outputs are forced high. LVCMOS / LVTTL interface levels.	
3	CLK_SEL	Input	Pulldown	Clock select input. When HIGH, selects PCLK/nPCLK inputs. When LOW, selects CLK/nCLK inputs. LVCMOS / LVTTL interface levels.	
4	CLK	Input	Pulldown	Non-inverting differential clock input.	
5	nCLK	Input	Pullup	Inverting differential clock input.	
6	PCLK	Input	Pulldown	Non-inverting differential LVPECL clock input.	
7	nPCLK	Input	Pullup	Inverting differential LVPECL clock input.	
8	OE	Input	Pullup	Output enable. Controls enabling and disabling of outputs Q0/nQ0 through Q3/nQ3. LVCMOS/LVTTL interface levels.	
10, 18	V_{DD}	Power		Positive supply pins.	
11, 12	nQ3, Q3	Output		Differential output pair. LVDS interface levels.	
14, 15	nQ2, Q2	Output		Differential output pair. LVDS interface levels.	
16, 17	nQ1, Q1	Output		Differential output pair. LVDS interface levels.	
19, 20	nQ0, Q0	Output		Differential output pair. LVDS interface levels.	

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ

Function Tables

Table 3A. Control Input Function Table

	Inp	Out	puts		
OE	OE CLK_EN CLK_SEL Selected Source		Q0:Q3	nQ0:nQ3	
0	X	Х		Hi-Z	Hi-Z
1	0	0	CLK/nCLK	Disabled; Low	Disabled; High
1	0	1	PCLK/nPCLK	Disabled; Low	Disabled; High
1	1	0	CLK/nCLK	Enabled	Enabled
1	1	1	PCLK/nPCLK	Enabled	Enabled

After CLK_EN switches, the clock outputs are disabled or enabled following a rising and falling input clock edge as shown in Figure 1. In the active mode, the state of the outputs are a function of the CLK/nCLK and PCLK/nPCLK inputs as described in Table 3B.

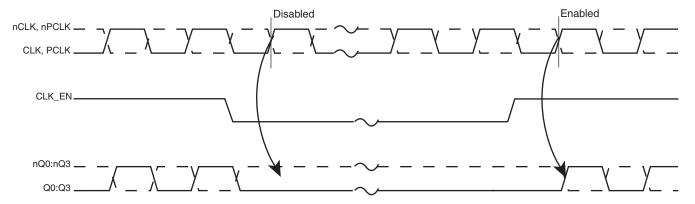


Figure 1. CLK_EN Timing Diagram

Table 3B. Clock Input Function Table

Inputs		Out	puts		
CLK or PCLK	nCLK or nPCLK	Q[0:3] nQ[0:3]		Input to Output Mode	Polarity
0	1	LOW	HIGH	Differential to Differential	Non-Inverting
1	0	HIGH	LOW	Differential to Differential	Non-Inverting
0	Biased; NOTE 1	LOW	HIGH	Single-Ended to Differential	Non-Inverting
1	Biased; NOTE 1	HIGH	LOW	Single-Ended to Differential	Non-Inverting
Biased; NOTE 1	0	HIGH	LOW	Single-Ended to Differential	Inverting
Biased; NOTE 1	1	LOW	HIGH	Single-Ended to Differential	Inverting

NOTE 1: Please refer to the Application Information section, Wiring the Differential Input to Accept Single-Ended Levels.

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V _{DD}	4.6V
Inputs, V _I	-0.5V to V _{DD} + 0.5V
Outputs, I _O Continuos Current Surge Current	10mA 15mA
Package Thermal Impedance, θ_{JA}	73.2°C/W (0 lfpm)
Storage Temperature, T _{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
I _{DD}	Power Supply Current				50	mA

Table 4B. LVCMOS/LVTTL DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $T_A = 0$ °C to 70°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Vol	tage		2		3.765	V
V _{IL}	Input Low Voltage					0.8	V
	Input	OE, CLK_EN	$V_{DD} = V_{IN} = 3.465V$			5	μΑ
Iн	High Current	CLK_SEL	$V_{DD} = V_{IN} = 3.465V$			150	μΑ
	Input	OE, CLK_EN	V _{DD} = 3.465V, V _{IN} = 0V	-150			μΑ
¹IL	Low Current	CLK_SEL	V _{DD} = 3.465V, V _{IN} = 0V	-5			μΑ

Table 4C. Differential DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $T_A = 0^{\circ}C$ to $70^{\circ}C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465V$			150	μA
I'IH	input riigii Current	nCLK	$V_{DD} = V_{IN} = 3.465V$			5	μA
	Input Low Current	CLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-5			μA
IIL.	Input Low Current	nCLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-150			μA
V_{PP}	Peak-to-Peak Voltag	e; NOTE 1		0.15		1.3	٧
V _{CMR}	Common Mode Input NOTE 1, 2	t Voltage;		0.5		V _{DD} – 0.85	V

NOTE 1: V_{IL} should not be less than -0.3V. NOTE 2: Common mode input voltage is defined as V_{IH} .

Table 4D. LVPECL DC Characteristics, $V_{DD}=3.3V\pm5\%,\,T_{A}=0^{\circ}C$ to $70^{\circ}C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
ı	P		$V_{DD} = V_{IN} = 3.465V$			150	μA
¹ ІН	Input High Current	nPCLK	$V_{DD} = V_{IN} = 3.465V$			5	μA
ı	lament Laur Commant	PCLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-5			μΑ
¹ L	Input Low Current	nPCLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-150			μA
V _{PP}	Peak-to-Peak Voltag	e; NOTE 1		0.3		1.0	٧
V _{CMR}	Common Mode Input NOTE 1, 2	t Voltage;		1.5		V _{DD}	٧

NOTE 1: V_{IL} should not be less than -0.3V.

NOTE 2: Common mode input voltage is defined as V_{IH} .

Table 4E. LVDS DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{OD}	Differential Output Voltage		200	280	360	mV
ΔV_{OD}	V _{OD} Magnitude Change			0	40	mV
V _{OS}	Offset Voltage		1.125	1.25	1.375	V
ΔV_{OS}	V _{OS} Magnitude Change			5	25	mV
l _{Oz}	High Impedance Leakage		-10		+10	μA
I _{OFF}	Power Off Leakage		-20	±1	+20	μΑ
I _{OSD}	Differential Output Short Circuit Current			-3.5	-5	mA
I _{OS}	Output Short Circuit Current			-3.5	-5	mA
V _{OH}	Output Voltage High			1.34	1.6	V
V_{OL}	Output Voltage Low		0.9	1.06		V

AC Electrical Characteristics

Table 5. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $T_A = 0$ °C to 70°C

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Maximum Output Frequency				800	MHz
t _{PD}	Propagation Delay; NOTE 1	<i>f</i> ≤ 800MHz	1.7		2.6	ns
tsk(o)	Output Skew; NOTE 2, 4				40	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4				500	ps
t _R / t _F	Output Rise/Fall Time	20% to 80% @ 50MHz	150		350	ps
odc	Output Duty Cycle odc		45	50	55	%

All parameters measured at 500MHz unless noted otherwise.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

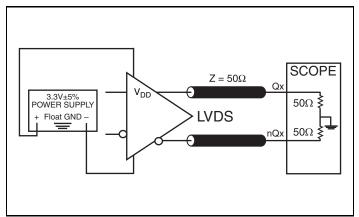
Measured at the differential output cross points.

NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions.

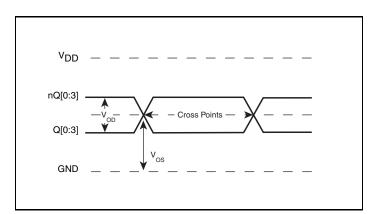
Using the same type of inputs on each device, the outputs are measured at the differential cross points.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

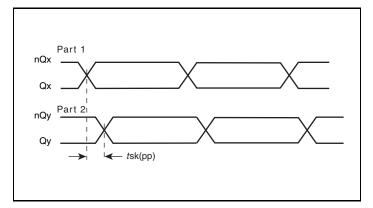
Parameter Measurement Information



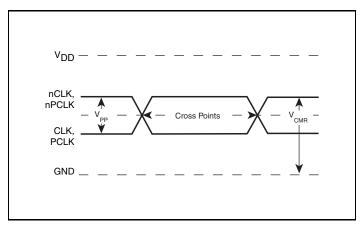
3.3V LVDS Output Load AC Test Circuit



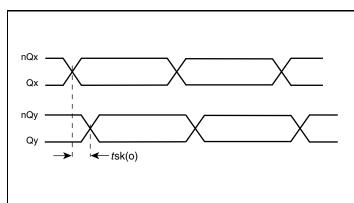
Differential Output Level



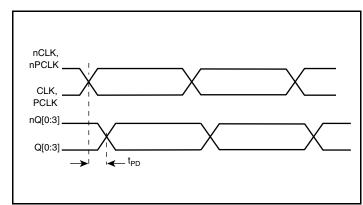
Part-to-Part Skew



Differential Input Level

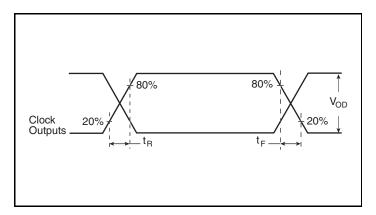


Output Skew



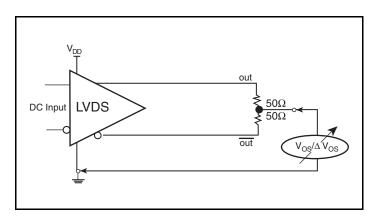
Propagation Delay

Parameter Measurement Information, continued

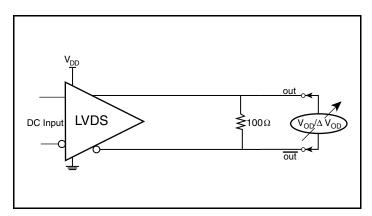


 $\begin{array}{c}
nQ[0:3] \\
Q[0:3] \\
& t_{PW} \\
& t_{PERIOD}
\end{array}$ $odc = \frac{t_{PW}}{t_{PERIOD}} \times 100\%$

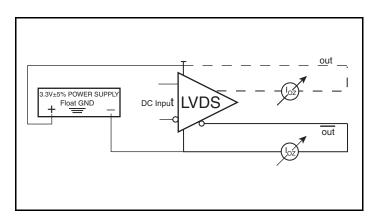
Output Rise/Fall Time



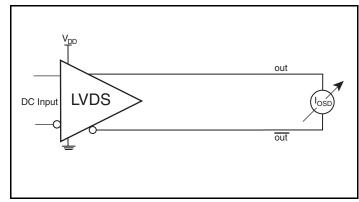
Output Duty Cycle/Pulse Width/Period



Offset Voltage Setup



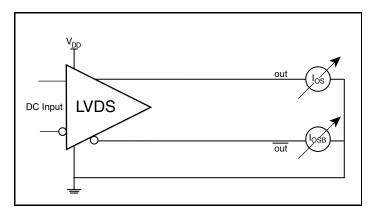
Differential Output Voltage Setup

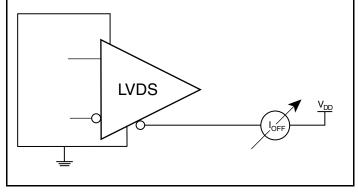


High Impedance Leakage Current Setup

Differential Output Short Circuit Setup

Parameter Measurement Information, continued





Output Short Circuit Current Setup

Power Off Leakage Setup

Application Information

Wiring the Differential Input to Accept Single Ended Levels

Figure 2 shows how the differential input can be wired to accept single ended levels. The reference voltage V_REF = $V_{DD}/2$ is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and $V_{DD} = 3.3V$, V_REF should be 1.25V and R2/R1 = 0.609.

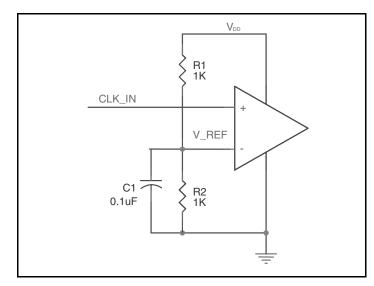


Figure 2. Single-Ended Signal Driving Differential Input

Differential Clock Input Interface

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both signals must meet the V_{PP} and V_{CMR} input requirements. Figures 3A to 3F show interface examples for the HiPerClockS CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. Please consult with the vendor of the driver

component to confirm the driver termination requirements. For example, in Figure 3A, the input termination applies for IDT HiPerClockS open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

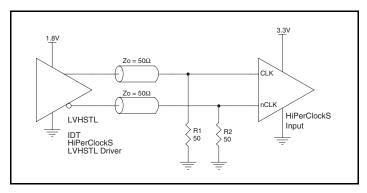


Figure 3A. HiPerClockS CLK/nCLK Input
Driven by an IDT Open Emitter
HiPerClockS LVHSTL Driver

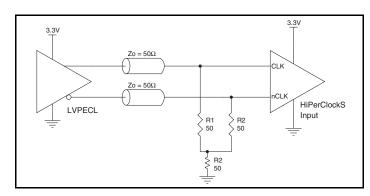


Figure 3B. HiPerClockS CLK/nCLK Input Driven by a 3.3V LVPECL Driver

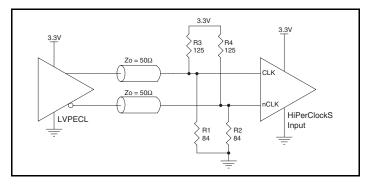


Figure 3C. HiPerClockS CLK/nCLK Input
Driven by a 3.3V LVPECL Driver

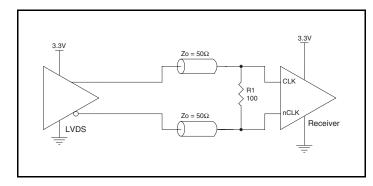


Figure 3D. HiPerClockS CLK/nCLK Input Driven by a 3.3V LVDS Driver

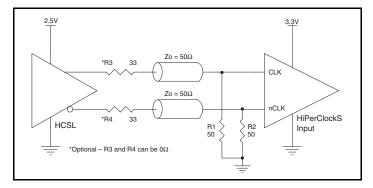


Figure 3E. HiPerClockS CLK/nCLK Input Driven by a 3.3V HCSL Driver

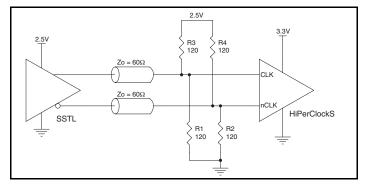


Figure 3F. HiPerClockS CLK/nCLK Input Driven by a 2.5V SSTL Driver

LVPECL Clock Input Interface

The PCLK /nPCLK accepts LVPECL, CML, SSTL and other differential signals. Both signals must meet the V_{PP} and V_{CMR} input requirements. Figures 4A to 4E show interface examples for the HiPerClockS PCLK/nPCLK input driven by the most common

driver types. The input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

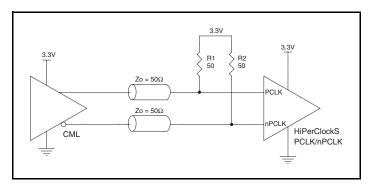


Figure 4A. HiPerClockS PCLK/nPCLK Input Driven by a CML Driver

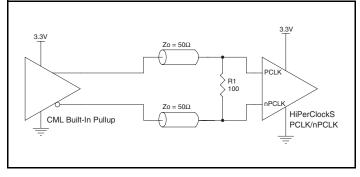


Figure 4B. HiPerClockS PCLK/nPCLK Input
Driven by a Built-In Pullup CML Driver

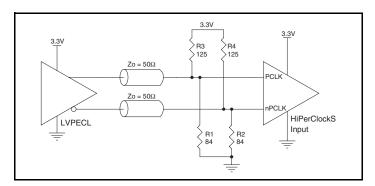


Figure 4C. HiPerClockS PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver

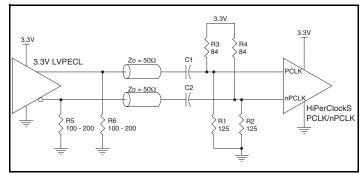


Figure 4D. HiPerClockS PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver with AC Couple

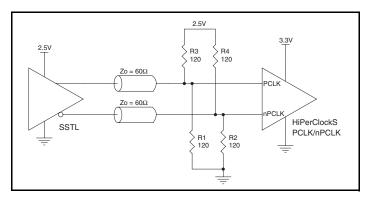


Figure 4E. HiPerClockS PCLK/nPCLK Input Driven by an SSTL Driver

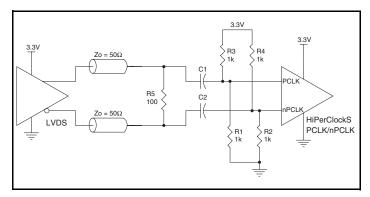


Figure 4F. HiPerClockS PCLK/nPCLK Input Driven by a 3.3V LVDS Driver

Recommendations for Unused Input and Output Pins

Inputs:

CLK/nCLK INPUTS

For applications not requiring the use of the differential input, both CLK and nCLK can be left floating. Though not required, but for additional protection, a $1k\Omega$ resistor can be tied from CLK to ground.

PCLK/nPCLK INPUTS

For applications not requiring the use of the differential input, both PCLK and nPCLK can be left floating. Though not required, but for additional protection, a $1k\Omega$ resistor can be tied from PCLK to ground.

LVCMOS Control Pins

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A $1k\Omega$ resistor can be used.

Outputs:

LVDS Outputs

All unused LVDS output pairs can be either left floating or terminated with 100 Ω across. If they are left floating, there should be no trace attached.

3.3V LVDS Driver Termination

A general LVDS interface is shown in Figure 5. In a 100Ω differential transmission line environment, LVDS drivers require a matched load termination of 100Ω across near the receiver input.

For a multiple LVDS outputs buffer, if only partial outputs are used, it is recommended to terminate the unused outputs.

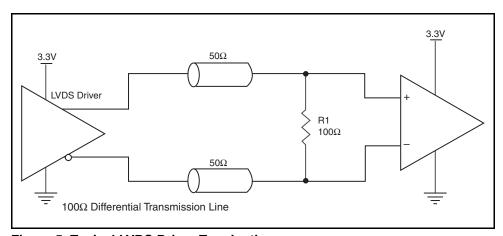


Figure 5. Typical LVDS Driver Termination

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS8543. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS8543 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{DD} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

Power (core)_{MAX} = V_{DD_MAX} * I_{DD_MAX} = 3.465V * 50mA = 173.25mW

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS devices is 125°C.

The equation for Tj is as follows: Tj = θ_{JA} * Pd_total + T_A

Tj = Junction Temperature

 θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 73.2°C/W per Table 6 below.

Therefore, Tj for an ambient temperature of 70°C with all outputs switching is:

 $70^{\circ}\text{C} + 0.173\text{W} * 73.2^{\circ}\text{C/W} = 827.7^{\circ}\text{C}$. This is well below the limit of 125°C .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (single layer or multi-layer).

Table 6. Thermal Resitance θ_{JA} for 20 Lead TSSOP, Forced Convection

θ _{JA} by Velocity				
Linear Feet per Minute	0	200	500	
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98.0°C/W	88.0°C/W	
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W	

Reliability Information

Table 7. θ_{JA} vs. Air Flow Table for a 20 Lead TSSOP

θ _{JA} by Velocity				
Linear Feet per Minute	0	200	500	
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98.0°C/W	88.0°C/W	
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W	

Transistor Count

The transistor count for ICS8543 is: 636

Package Outline and Package Dimensions

Package Outline - G Suffix for 20 Lead TSSOP

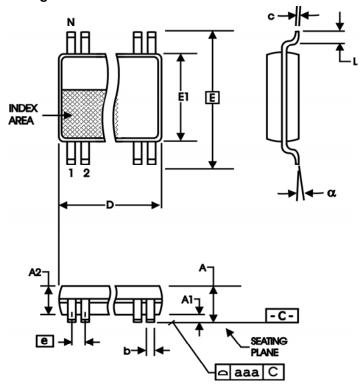


Table 8. Package Dimensions

All Dimensions in Millimeters				
Symbol	Minimum Maximum			
N	20			
Α		1.20		
A 1	0.05	0.15		
A2	0.80	1.05		
b	0.19	0.30		
С	0.09	0.20		
D	D 6.40 6.60			
E	6.40 Basic			
E1	4.30	4.50		
е	0.65 Basic			
L	0.45	0.75		
α	0° 8°			
aaa		0.10		

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
ICS8543BG	ICS8543BG	20 Lead TSSOP	Tube	0°C to 70°C
ICS8543BGT	ICS8543BG	20 Lead TSSOP	2500 Tape & Reel	0°C to 70°C
ICS8543BGLF	ICS8543BGLF	"Lead-Free" 20 Lead TSSOP	Tube	0°C to 70°C
ICS8543BGLFT	ICS8543BGLF	"Lead-Free" 20 Lead TSSOP	2500 Tape & Reel	0°C to 70°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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Revision History Sheet

Rev	Table	Page	Description of Change	Date
Α	T4E	5	In the $V_{\mbox{\scriptsize OL}}$ row, 1.06 has been moved to the Typical column from the maximum column.	9/18/01
Α		3	Updated Figure 1, CLK_EN Timing Diagram.	10/17/01
Α		3	Updated Figure 1, CLK_EN Timing Diagram.	11/2/01
Α		1 6 - 10	Features section, Bullet 6 to read 3.3V LVDS levels instead of LVPECL. Updated Parameter Measurement Information figures.	5/6/02
В	T5	5	AC Characteristics table - revised Output Frequency from 650MHz to 800MHz.	6/5/02
С		1	Features - deleted bullet ""Designed to meet or exceed the requirements of ANSI TIA/EIA-644"".	9/19/02
	4E 5 LVDS Table - changed V _{OD} typical value fro		LVDS Table - changed $V_{\mbox{\scriptsize OD}}$ typical value from 350mV to 280mV.	
D	T2	2 4 9 10 11	Pin Characteristics - changed C _{IN} 4pF max. to 4pF typical. Absolute Maximum Ratings - changed Output rating. Added Differential Clock Input Interface section. Added LVPECL Clock Input Interface section. Added LVDS Driver Termination section. Updated format throughout data sheet.	12/31/03
D	T1	2	Pin Description table - added function description to the OE pin.	4/7/04
D	Т8	10 13	Updated LVPECL CLock Input Interface section. Added Lead Free part number to Ordering Information table.	6/16/04
D		3 10 11 12 13	Updated Figure 1, CLK_EN Timing Diagram. Updated Differential Clock Input Interface section. Updated LVPECL Clock Input Interface section. Added Recommendation for Unused Input and Output Pins section. Added Power Considerations section. Updated format throughout the datasheet.	

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